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EXCHANGE INTERACTION IN ZnCrSe SEMIMAGNETIC SEMICONDUCTOR*

W. MAC, NGUYEN THE KHOI[†], A. TWARDOWSKI, J.A. GAJ

Institute of Experimental Physics, Warsaw University Hoża 69, 00-681 Warszawa, Poland

AND M. DEMIANIUK

Institute of Technical Physics, W.A.T., Warszawa, Poland

Magnetoreflectance and magnetization of ZnCrSe were measured for $B \leq 5$ T and T = 2 K. A linear dependence between exciton splitting and magnetization was found. The s, p-d exchange parameter was estimated: $N_0\alpha - N_0\beta = 0.67$ eV.

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The most popular semimagnetic or diluted magnetic semiconductors (DMS) are materials with Mn, Co and Fe as the magnetic ions [1]. In all of them a strong exchange interaction between magnetic ions and band carriers has been observed. It seems rather well established that in these materials the p-d exchange results mostly from the hybridization of d orbitals (3 t-type and 2 e-type) with the valence band. In the centre of the Brillouin zone only the t-orbitals hybridize with the valence band. From this point of view the situation for Mn-, Co- and Fe-DMS is similar, since for all of them t-orbitals are singly occupied (Mn: $d^5 =$ $t_{+}^{3}e_{+}^{2}$, Fe: $d^{6} = t_{+}^{3}e_{+}^{2}e_{-}^{1}$, Co: $d^{7} = t_{+}^{3}e_{+}^{2}e_{-}^{2}$). In such a case, a simple isotropic Heisenberg Hamiltonian constitutes a good approximation for the p-d exchange [2], and band splittings should be parametrized by macroscopic magnetization. In fact, such behaviour was encountered in the experiment [1]. The situation for Cr-DMS is different: two t orbitals are occupied and the remaining one is empty $(d^4 = t_+^2 e_+^2)$. In this case non-Heisenberg terms in the Hamiltonian are expected [2, 0.005. Magnetoreflectivity from the (110) surface was measured in the range of the fundamental absorption edge at T = 2 K and an exciton line was observed. In the presence of a magnetic field $(B = 0 \div 5 \text{ T}, \text{Faraday configuration})$ the exciton line splits into two components (each visible in one of the circular polarizations). We recall that for other DMS the exciton line splits into four components [1]: lines A, B (σ^+ polarization) and C, D (σ^- polarization). We believe that due to

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[†]On leave from Pedagogical University, Hanoi

small splittings and rather large width of the exciton lines, the lines in the same polarization are not resolved in our case. Therefore, the $\sigma^+(\sigma^-)$ exciton line is composed of unresolved lines A and B (C and D). Since line A (D) is 3 times stronger than line B (C), we assume that the observed exciton line represents mostly line A (D). The Zeeman splittings observed in this work exhibit opposite sign to that usually reported in DMS (we observed that σ^+ component at a higher energy than the σ^- component).

Magnetization (measured on the same samples on which optical work was done) shows typical paramagnetic behaviour. It was found to obey a crystal field model calculation [3] performed for isolated ions. Cr mole fraction values obtained from fitting the absolute magnetization are indicated in Fig. 1. The form of the magnetization does not follow the Brillouin law in contrast to DMS studied so far. The exciton splitting was found to be linear with the magnetization (Fig. 2),



Fig. 1. Magnetization of several samples of various Cr^{++} mole fraction values, plotted vs. magnetic field. $\diamond 0.45\%$, + 0.35%, $\bigtriangledown 0.31\%$, $\Box 0.23\%$, $\bigcirc 0.10\%$. Lines are fits with crystal field model [4].

Fig 2. Exciton splitting $E_{\rm A} - E_{\rm D}$ vs. magnetization for four samples of various Cr⁺⁺ mole fraction values. $\diamond 0.45\%$, $\bigtriangledown 0.35\%$, $\Box 0.23\%$, $\bigcirc 0.10\%$. Line represents linear dependence with the slope 70 cm⁻¹g/emu.

similarly as it was for the other DMS [1, 4]. Hence our results give no grounds for introducing any non-Heisenberg terms in carrier-ion interaction. Having in mind the limited magnetic ion concentration range and therefore small accuracy of our data, we do not exclude the presence of such terms.

Assuming a conventional isotropic Heisenberg-like form of the exchange interaction we get [4]

$$E_{\rm D} - E_{\rm A} = (N_0 \alpha - N_0 \beta) x(S) = (N_0 \alpha - N_0 \beta) m k M_{\rm m} / \mu_{\rm B},$$

where $\langle S \rangle$ is the mean spin of Cr⁺⁺ ion, $\alpha = \langle S|J|S \rangle$, $\beta = \langle X|J|X \rangle$ are exchange integrals for the conduction and valence bands, respectively [1], $m = (1-x)m_{\rm Zn} + x m_{\rm Cr} + m_{\rm Se} = m_{\rm mole}/N_{\rm Av}$ is the mass of a DMS molecule, $\mu_{\rm B}$ is the Bohr magneton, $M_{\rm m}$ is the macroscopic magnetization and $k = \langle S \rangle / \langle M \rangle = 0.53$ [3] is the ratio of the mean magnetic moment and mean spin of the Cr ion (k = 1/2 for the spin only case).

It follows from the data shown in Fig. 2 that $E_A - E_D = (70 \text{ cm}^{-1} \text{ g/emu}) M_m$ (with an accuracy of 10 %), which corresponds to the exchange parameter $(N_0\alpha - N_0\beta) = -0.67 \text{ eV}$. A simple way of taking into account the contribution of weak exciton components B and C would consist in multiplication of $(N_0\alpha - N_0\beta)$ by a factor 4/3, producing a correct value $(N_0\alpha - N_0\beta) = 0.9 \text{ eV}$. These values are of the same order as those found for the other DMS, typically between 1.1 eV (CdMnTe) and 2.5 eV (ZnCoSe), only the sign is opposite. A possible reason for the observed value of the exchange parameter is a new mechanism present in p-d exchange for the d^4 electronic configuration. Roughly speaking one unoccupied t orbital provides an additional exchange path, which leads to ferromagnetic p-d coupling [5]. This ferromagnetic exchange may exceed the typical anti-ferromagnetic exchange (observed for Mn-, Co- and Fe-DMS [1, 2]).

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